Transistors Panasonic

## 2SD2345J

## Silicon NPN epitaxial planar type

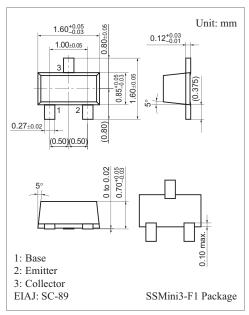
For low frequency amplification

#### ■ Features

- High forward current transfer ratio h<sub>FE</sub>
- $\mbox{\ensuremath{\blacksquare}}$  Low collector-emitter saturation voltage  $V_{\text{CE(sat)}}$
- ullet High emitter-base voltage (Collector open)  $V_{EBO}$
- Low noise voltage NV

### ■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	$V_{CBO}$	50	V	
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	40	V	
Emitter-base voltage (Collector open)	V <sub>EBO</sub>	V <sub>EBO</sub> 15		
Collector current	$I_{C}$	50	mA	
Peak collector current	I <sub>CP</sub>	I <sub>CP</sub> 100		
Collector power dissipation	P <sub>C</sub>	125	mW	
Junction temperature	T <sub>j</sub>	125	°C	
Storage temperature	T <sub>stg</sub>	-55 to +125	°C	



Marking Symbol: 1Z

### ■ Electrical Characteristics $T_a = 25$ °C±3°C

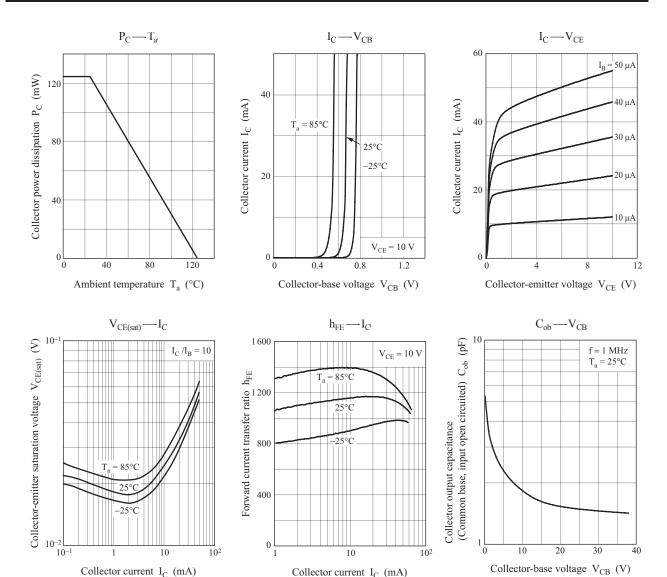
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	$I_{\rm C} = 10 \ \mu A, I_{\rm E} = 0$	50			V
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	$I_{CI} = 1 \text{ mA}, I_{B} = 0$	40			V
Emitter-base voltage (Collector open)	$V_{EBO}$	$I_{\rm E} = 10  \mu A, I_{\rm C} = 0$	15			V
Collector-base cutoff current (Emitter open)	$I_{CBO}$	$V_{CB} = 20 \text{ V}, I_{E} = 0$			0.1	μΑ
Collector-emitter cutoff current (Base open)	I <sub>CEO</sub>	$V_{CH} = 20 \text{ V}, I_B = 0$			1	μΑ
Forward current transfer ratio *	h <sub>FE</sub>	$V_{CH} = 10 \text{ V}, I_{C} = 2 \text{ mA}$	600		2000	_
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_{\rm Cl} = 10 \text{ mA}, I_{\rm B} = 1 \text{ mA}$		0.05	0.2	V
Transition frequency	$f_T$	$V_{CB} = 10 \text{ V}, I_{E} = -2 \text{ mA}, f = 200 \text{ MHz}$		120		MHz

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

#### 2. \*: Rank classification

Rank	S	Т
$h_{ m FE}$	600 to 1200	1000 to 2000

**Panasonic** 2SD2345J



Collector current  $I_C$  (mA)

2 SJC00337AED

Collector current  $I_C$  (mA)

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